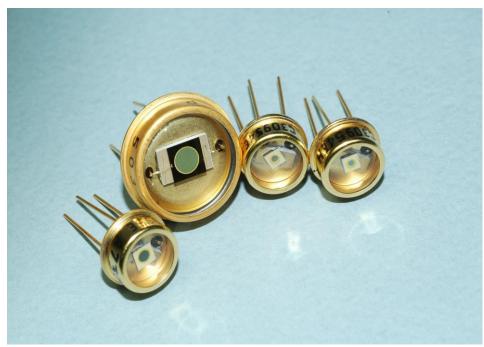
### C30954EH, C30955EH and C30956EH Series

## Long Wavelength Enhanced Silicon Avalanche Photodiodes



Reach through 1064nm quantum efficiency enhanced silicon avalanche photodiode.

### **Key Features**

- High Quantum Efficiency at 1060nm
- Fast Response Time
- Wide operating Temperature Range
- Hermetically sealed packages

#### **Applications**

- Range finding
- LIDAR
- YAG Laser Detection

Excelitas' C30954EH, C30955EH, and C30956EH are general purpose silicon avalanche photodiodes made using a double-diffused "reach through" structure. The design of these photodiodes is such that their long wave response (i.e. > 900 nm) has been enhanced without introducing any undesirable properties.

These APDs have quantum efficiency of up to 40% at 1060 nm. At the same time, the diodes retain the low noise, low capacitance, and fast rise and fall times characteristics.

Standard versions of these APDs are available in hermetically-sealed, flat top glass TO-5 packages for the smaller area C30954EH and C30955EH, and a TO-8 package for the larger area C30956EH.

To help simplify many design needs, these Si APDs are also available in Excelitas' high-performance hybrid preamplifier module, C30659 Series, as well as the preamplifier and Thermo-electric (TE) cooler incorporated module, the LLAM Series.

Recognizing that different applications have different performance requirements, Excelitas offers a wide range of customization options for these APDs to meet your design challenges. TE cooler-packaged versions are available on a custom basis. Operating and breakdown voltage selection, dark current and NEP screening, custom device testing and packaging are among the many application-specific solutions available.

**Table 1 – Mechanical and Optical Characteristics** 

Parameter	Symbol	С30954ЕН	С30955ЕН	С30956ЕН	Unit
Shape		Circular	Circular	Circular	
Package		TO-5	TO-5	TO-8	
Photosensitive Surface: Useful area Useful diameter	A d	0.5 0.8	1.77 1.5	7 3	mm² mm
Field of View: Nominal field of view $\alpha$ (see Figure 10) Nominal field of view $\alpha'$ (see Figure 10)	FoV	110 125	104 130	135 150	Degrees

**Table 2 – Electro-Optical Characteristics** 

Case Temperature  $T_A = 22$  °C; at the DC reverse operating voltage V,  $V_{op}^{1}$ 

Parameter	Symbol	С30954ЕН		С30955ЕН		С30956ЕН		Unit			
		Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	
Breakdown Voltage	$V_{br}$	300	375	475	315	390	490	325	400	500	V
Temperature Coefficient of V <sub>op</sub> for Constant M	V <sub>op</sub>		2.4			2.4			2.4		V/°C
Gain	М		120			100			75		
Responsivity at 900 nm at 1060 nm at 1150 nm	R	65 30 4	75 36 5		55 26 4	70 34 5		36 20 2.8	45 25 3.5		A/W
Quantum Efficiency at 900 nm at 1060 nm at 1150 nm	Q.E.		85 36 5			85 40 5			85 40 5		%
Total Dark Current	I <sub>d</sub>		50	100		100	200		100	200	nA
Noise Current f=10kHz, Δf=1.0Hz	i <sub>n</sub>		1	2		1	2		1.1	2.2	pA/√Hz
Capacitance	$C_d$		2	4		3	5		10	12	pF
Series resistance	$R_s$			15			15			15	Ω
Rise/Fall Time, $R_L = 50\Omega$ : 10% to 90% points 90% to 10% points	t <sub>r</sub> t <sub>f</sub>		2 2	3 3		2 2	3.5 3.5		2 2	3.5 3.5	ns

 $<sup>^{1}</sup>$  A specific value of  $V_R$  is supplied with each device. When the photodiode is operated at this voltage, the device will meet the electrical characteristic limits shown above. The voltage value will be within the range of 275 to 450 volts.

1

### C30954-955-956EH Series

Table 3 – Absolute – Maximum Ratings, Limiting Values

Parameter	Symbol	Minimum	Typical	Maximum	Unit	Remarks/Conditions
Reverse Bias Current				200	μΑ	
Photocurrent Density : average value peak value	$J_p$			5 20	mA/mm²	Continuous operation
Forward Current: average value peak value	I <sub>F</sub>			5 50	mA	Continuous operation (For 1 second duration, non-repetitive)
Storage Temperature	$T_{stg}$	-60		100	°C	
Operating Temperature	T <sub>o</sub>	-40		70	°C	
Soldering				260	°C	5 seconds, leads only



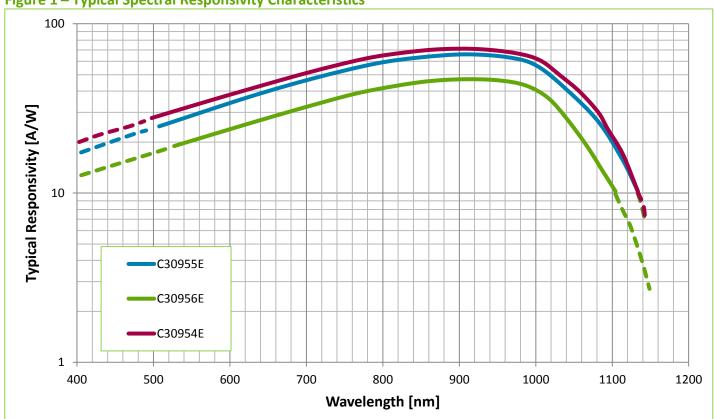


Figure 2 – Typical Responsivity at 900 nm as a function of Operating Voltage, V<sub>op</sub> (C30954EH)

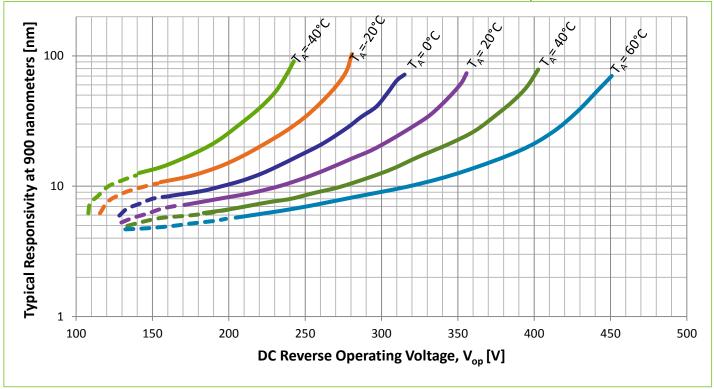


Figure 3 – Typical Responsivity at 900 nm as a function of Operating Voltage, Vop (C30955EH)

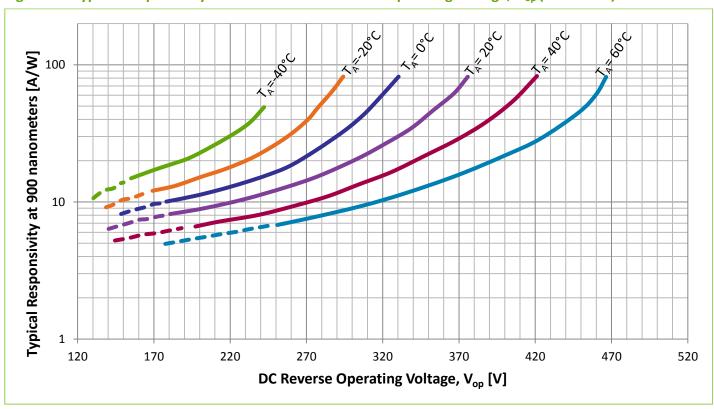


Figure 4 – Typical Responsivity at 900 nm as a function of Operating Voltage, V<sub>op</sub> (C30956EH)

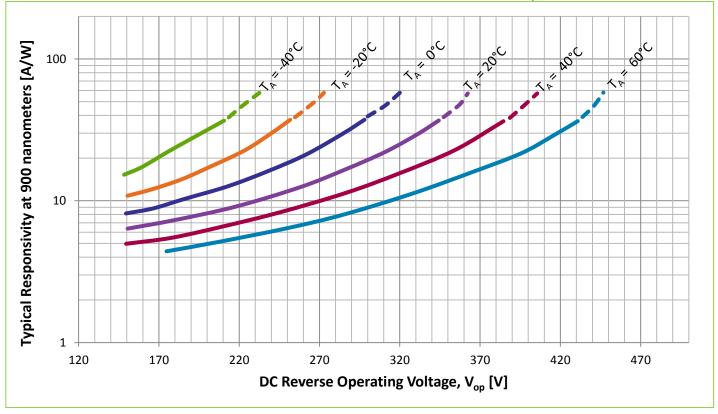


Figure 5 – Typical Responsivity at 1060 nm as a function of Operating Voltage, V<sub>op</sub> (C30954EH)

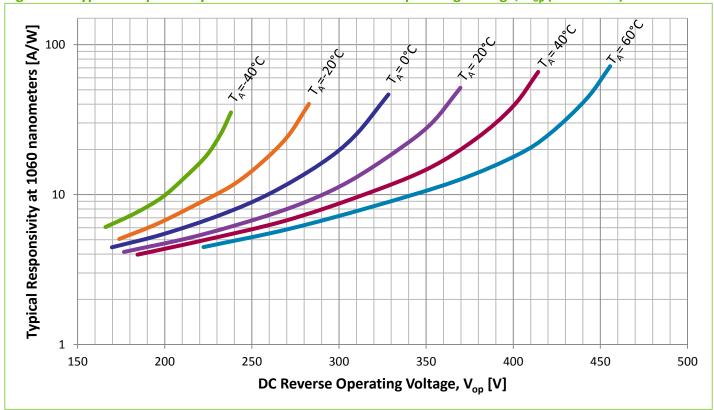


Figure 6 – Typical Responsivity at 1060 nm as a function of Operating Voltage, V<sub>op</sub> (C30955EH)

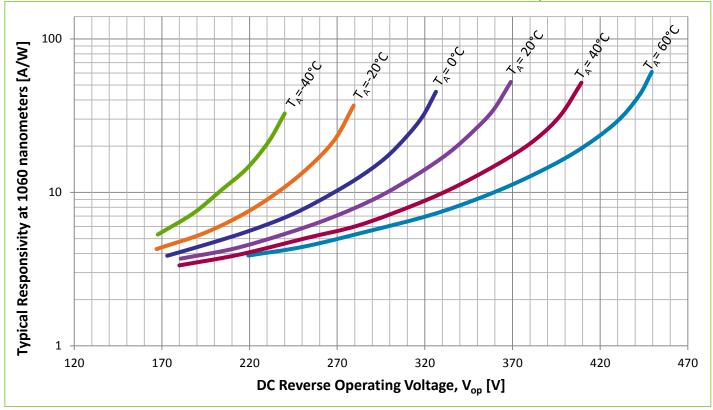
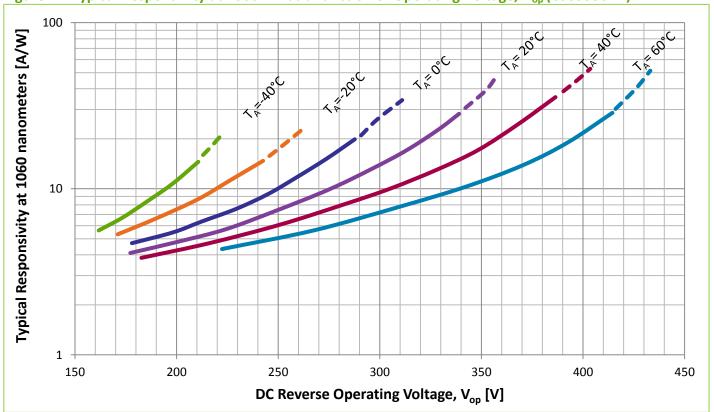


Figure 7 – Typical Responsivity at 1060 nm as a function of Operating Voltage, V<sub>op</sub> (C309556EH)





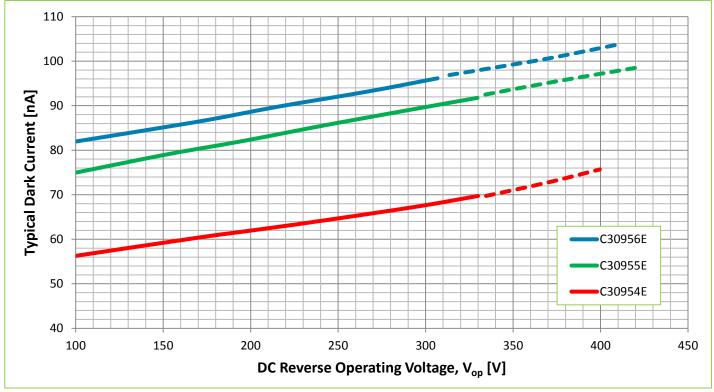
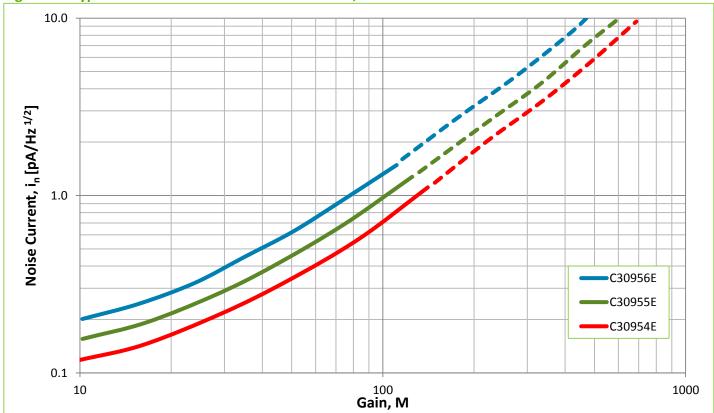


Figure 9 – Typical Noise Current as a function of Gain, M



### Figure 10 - Approximate Field of View

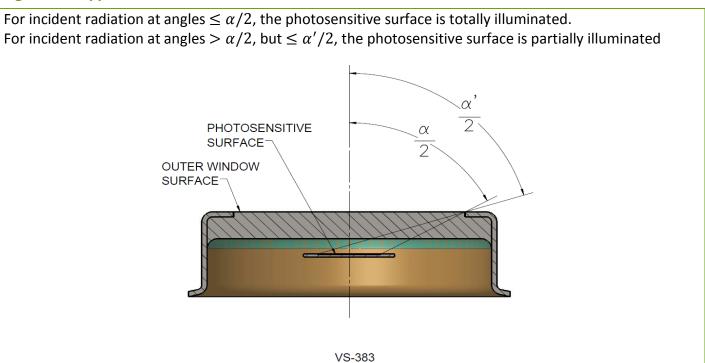


Figure 11 – Variation of Gain as a function of Difference between Actual Applied Operating Voltage and Recommended Operating Voltage,  $V_{op}$  (C30954EH)

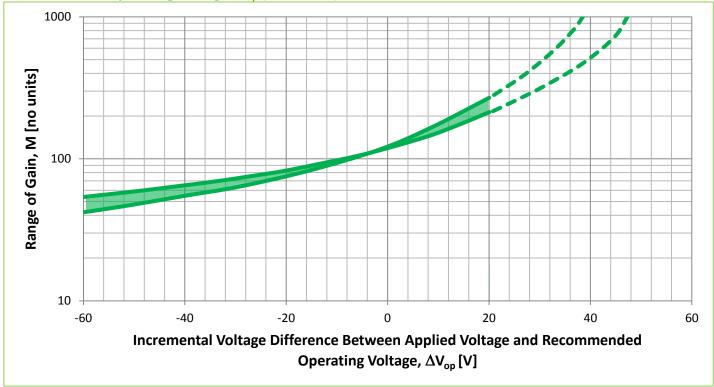


Figure 12 – Variation of Gain as a function of Difference between Actual Applied Operating Voltage and Recommended Operating Voltage,  $V_{\rm op}$  (C30955EH)

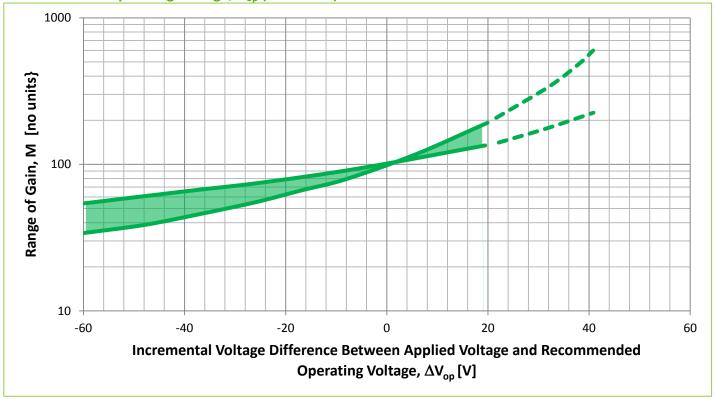
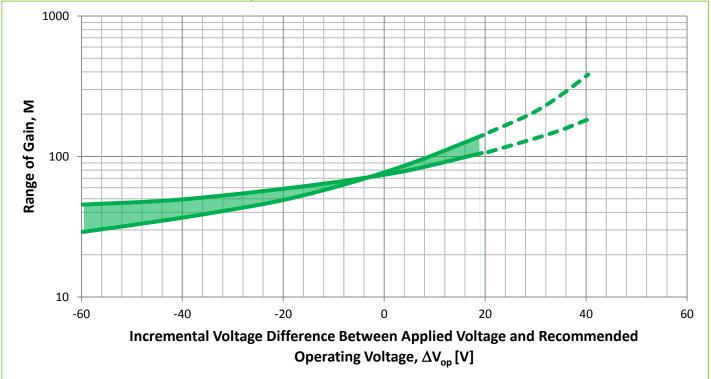


Figure 13 – Variation of Gain as a function of Difference between Actual Applied Operating Voltage and Recommended Operating Voltage, V<sub>op</sub> (C30956EH)



#### C30954-955-956EH Series

Figure 14 – Dimensional Outline (C30954EH, C30955EH Types) Low-Profile TO-5 Package, dimensions in mm (inch)

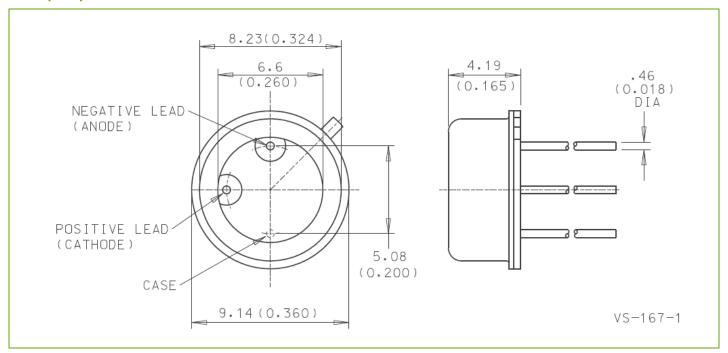
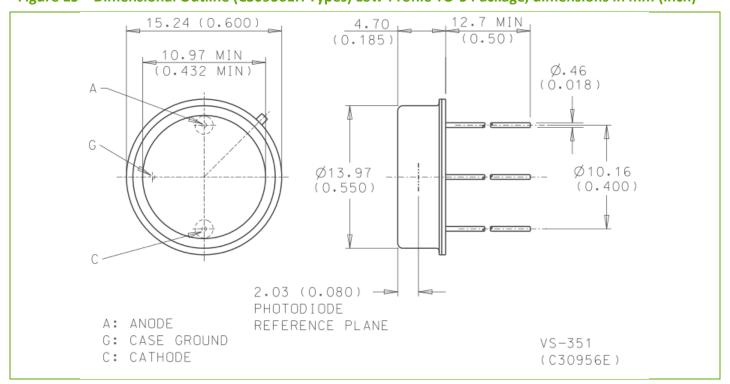


Figure 15 – Dimensional Outline (C30956EH Types) Low-Profile TO-5 Package, dimensions in mm (inch)



### **RoHS Compliance**

The C30954EH, C30955EH and C30956EH Avalanche photodiodes are designed and built to be fully compliant with the European Union Directive 2011/65/EU – Restriction of the use of certain Hazardous Substances (RoHS) in Electrical and Electronic equipment.



#### Warranty

A standard 12-month warranty following shipment applies. Any warranty is null and void if the photodiode window has been opened.

### **About Excelitas Technologies**

Excelitas Technologies is a global technology leader focused on delivering innovative, customized solutions to meet the lighting, detection and other high-performance technology needs of OEM customers.

Excelitas has a long and rich history of serving our OEM customer base with optoelectronic sensors and modules for more than 45 years beginning with PerkinElmer, EG&G, and RCA. The constant throughout has been our innovation and commitment to delivering the highest quality solutions to our customers worldwide.

From analytical instrumentation to clinical diagnostics, medical, industrial, safety and security, and aerospace and defense applications, Excelitas Technologies is committed to enabling our customers' success in their specialty end-markets. Excelitas Technologies has approximately 3,000 employees in North America, Europe and Asia, serving customers across the world.

**Excelitas Technologies** 

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